NSN 5961-01-100-4180

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View Online at https://aerobasegroup.com/nsn/5961-01-100-4180 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, collector-to-base, emitter open and 15.0 breakdown voltage, collector-to-emitter, base open and 3.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 30.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 80131-release5916 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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